SIEMENS

Data sheet 3RF2330-1DA44



Solid-state contactor 1-phase 3RF2 AC 51 / 30 A / 40 $^{\circ}$ C 48-460 V / 4-30 V DC short circuit-proof up to 25 A with B miniature circuit breaker

product brand name	SIRIUS
product designation	solid-state contactor
design of the product	single-phase
product type designation	3RF23
manufacturer's article number	
 _1 of the accessories that can be ordered 	3RF2900-3PA88
 _3 of the accessories that can be ordered 	3RF2900-0EA18
 _4 of the accessories that can be ordered 	3RF2950-0GA16
_5 of the accessories that can be ordered	3RF2920-0FA08
product designation	
_1 of the accessories that can be ordered	terminal cover
 _3 of the accessories that can be ordered 	converter
 _4 of the accessories that can be ordered 	load monitoring
_5 of the accessories that can be ordered	load monitoring, basis
General technical data	
product function	short-circuit resistant with B-automatic device
power loss [W] for rated value of the current	
at AC in hot operating state	33 W
at AC in hot operating state per pole	33 W
without load current share typical	0.6 W
insulation voltage rated value	600 V
degree of pollution	3
type of voltage	
of the operating voltage	AC
of the control supply voltage	DC
surge voltage resistance of main circuit rated value	6 kV
protection class IP	IP20
protection class IP on the front according to IEC 60529	IP20
shock resistance according to IEC 60068-2-27	15g / 11 ms
vibration resistance according to IEC 60068-2-6	2g
reference code according to IEC 81346-2	Q
Substance Prohibitance (Date)	05/28/2009
SVHC substance name	Lead - 7439-92-1 Lead monoxide (lead oxide) - 1317-36-8 Dibutylbis(pentane-2,4-dionato-O,O')tin - 22673-19-4
Weight	0.19 kg
Main circuit	
number of poles for main current circuit	1
number of NO contacts for main contacts	1
number of NC contacts for main contacts	0
type of voltage of the operating voltage	AC

operating voltage	
• at AC	
— at 50 Hz rated value	48 460 V
— at 60 Hz rated value	48 460 V
operating frequency rated value	50 60 Hz
operating range relative to the operating voltage at AC	
● at 50 Hz	40 506 V
● at 60 Hz	40 506 V
operational current	
• at AC-51 rated value	30 A
• at AC-51 according to IEC 60947-4-3	18.5 A
according to UL 508 rated value	26 A
operational current minimum	500 mA
operational current of the MCB at AC rated value	25 A
rate of voltage rise at the thyristor for main contacts maximum permissible	1 000 V/µs
blocking voltage at the thyristor for main contacts maximum permissible	1 200 V
reverse current of the thyristor	10 mA
derating temperature	40 °C
surge current resistance rated value	1 150 A
I2t value maximum	6 600 A²·s
Control circuit/ Control	
type of voltage of the control supply voltage	DC
control supply voltage 1 at DC rated value maximum permissible	30 V
control supply voltage 1 at DC	4 30 V
control supply voltage	
 at DC initial value for signal <1> detection 	4 V
at DC full-scale value for signal<0> recognition	1 V
control current at minimum control supply voltage	
• at DC	18 mA
control current at DC rated value	20 mA
ON-delay time	1 ms; additionally max. one half-wave
OFF-delay time Auxiliary circuit	1 ms; additionally max. one half-wave
	normally open contact (NO)
type of switching contact	normally open contact (NO) 0
number of NC contacts for auxiliary contacts number of NO contacts for auxiliary contacts	0
number of CO contacts for auxiliary contacts	0
Installation/ mounting/ dimensions	
fastening method side-by-side mounting	Yes
fastening method	screw fixing and snap-on mounting on standard mounting rail 35 mm according to IEC 60715
design of the thread of the screw for securing the	M4
equipment	05 mm
height	95 mm
width	22.5 mm 120 mm
depth Connections/ Terminals	120 11 1
	Yes
product component removable terminal for auxiliary and control circuit	160
type of electrical connection	
for main current circuit for auxilian and control circuit	screw-type terminals
• for auxiliary and control circuit	screw-type terminals
type of connectable conductor cross-sections	
• for main contacts	2v (1.5 2.5 mm²) 2v (2.5 6 mm²)
— solid	2x (1.5 2.5 mm²), 2x (2.5 6 mm²)
 finely stranded with core end processing for AWG cables for main contacts 	2x (1 2.5 mm²), 2x (2.5 6 mm²), 1x 10 mm²
onnectable conductor cross-section for main contacts	2x (14 10)
solid or stranded	1.5 6 mm²

finely stranded with core end processing	1 10 mm²
type of connectable conductor cross-sections	
 for auxiliary and control contacts 	
— solid	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
 finely stranded with core end processing 	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
finely stranded without core end processing	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
for AWG cables for auxiliary and control contacts	1x (AWG 20 12)
AWG number as coded connectable conductor cross section for	14 10
main contacts	10
tightening torque	
 for main contacts with screw-type terminals 	2 2.5 N·m
 for auxiliary and control contacts with screw-type terminals 	0.5 0.6 N·m
tightening torque [lbf·in]	
 for main contacts with screw-type terminals 	18 22 lbf·in
 for auxiliary and control contacts with screw-type terminals 	4.5 5.3 lbf-in
design of the thread of the connection screw	
• for main contacts	M4
of the auxiliary and control contacts	M3
stripped length of the cable	
for main contacts	7 mm
for auxiliary and control contacts Floatrical Cafety	7 mm
Electrical Safety	IDOS
protection class IP on the front according to IEC 60529	IP20
touch protection on the front according to IEC 60529	finger-safe, for vertical contact from the front
Ambient conditions	
installation altitude at height above sea level maximum	1 000 m
ambient temperature	
 during operation 	-25 +60 °C
during storage	-55 +80 °C
Electromagnetic compatibility	
conducted interference	
conducted interference	2 kV / 5 kHz behavior criterion 2
conducted interference • due to burst according to IEC 61000-4-4	
conducted interference	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2
conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC	2 kV behavior criterion 2
conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-	2 kV behavior criterion 2 1 kV behavior criterion 2
conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1
conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1
conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2
conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
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conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at NH design usable	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335
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conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable manufacturer's article number of the gG fuse	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 3NC1450 3NC2263
conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 12 x 58 mm usable manufacturer's article number of the gG fuse • at NH design usable	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 3NC1450 3NC2263 3NA6807: These fuses have a smaller rated current than the semiconductor relays
conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 12 x 58 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable manufacturer's article number of the gG fuse	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 3NC1450 3NC2263

manufacturer's article number

- of DIAZED fuse usable
- of NEOZED fuse usable

5SB2711; These fuses have a smaller rated current than the semiconductor relays

5SE2320: These fuses have a smaller rated current than the semiconductor relays

Approvals Certificates

General Product Approval

EMV





Confirmation







Test Certificates

other

Railway

Environment

Special Test Certificate

Type Test Certificates/Test Report

Confirmation



Special Test Certificate

Environmental Confirmations

Further information

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3RF2330-1DA44

Cax online generator

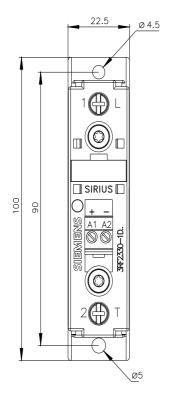
 $\underline{\text{http://support.automation.siemens.com/WW/CAXorder/default.aspx?lang=en\&mlfb=3RF2330-1DA44}$

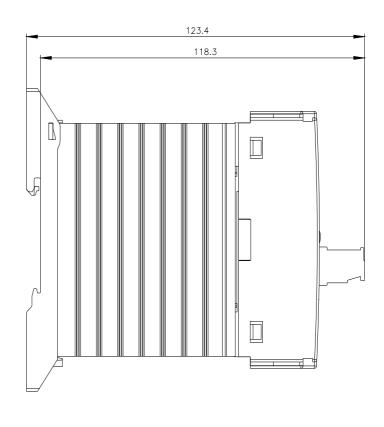
Service&Support (Manuals, Certificates, Characteristics, FAQs,...)

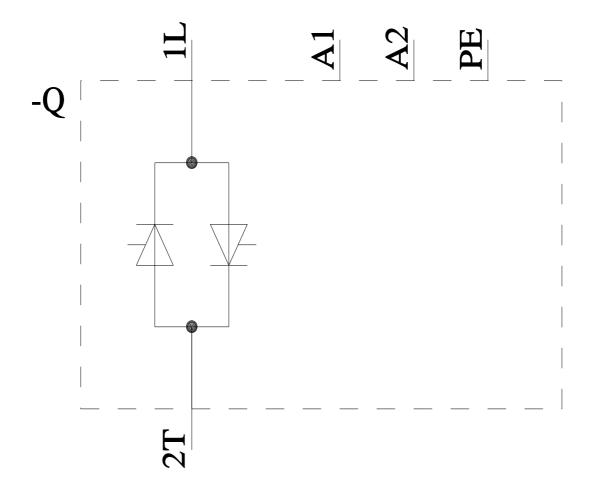
https://support.industry.siemens.com/cs/ww/en/ps/3RF2330-1DA44

Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...)

http://www.automation.siemens.com/bilddb/cax_de.aspx?mlfb=3RF2330-1DA44&lang=en







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